

Contents

1	General Introduction: Smart Materials, Sensors, and Actuators	1
1.1	Smart System	2
1.2	Device Application of Ferroelectric Materials	5
1.2.1	Piezoelectric Device Applications	6
1.2.2	Infrared Sensor	7
1.2.3	Ferroelectric RAM (FeRAM)	8
1.3	Device Application of Ferromagnetic Materials	9
1.3.1	Spin-Transfer Torque Memory	9
1.3.2	Magnetic Field Sensor Based on Multiferroic Device	9
1.4	Ferroelastic Material and Device Application	10
1.5	Scope of This Book	12
	References	13
2	Introduction to Ferroelectrics	15
2.1	What Is Ferroelectrics?	15
2.1.1	P - E Loop	15
2.1.2	Relationships Between Dielectric, Piezoelectric, Pyroelectric, and Ferroelectric	16
2.1.2.1	Ferroelectric-Dielectric	16
2.1.2.2	Ferroelectric-Piezoelectric	17
2.1.2.3	Ferroelectric-Pyroelectric	18
2.2	Origin of Ferroelectrics	18
2.2.1	Structure-Induced Phase Change from Paraelectric to Ferroelectric	18
2.2.2	Soft Phonon Mode	19
2.3	Theory of Ferroelectric Phase Transition	21
2.3.1	Landau Free Energy and Curie-Weiss Law	21
2.3.2	Landau Theory of First-Order Phase Transition	23
2.3.3	Landau Theory of a Second-Order Phase Transition	26
2.4	Ferroelectric Domains and Domain Switching	28
2.4.1	Domain Structure	28
2.4.2	Ferroelectric Switching	28
2.5	Ferroelectric Materials	29

2.5.1	From BaTiO ₃ to SrTiO ₃	29
2.5.2	From PbTiO ₃ to PbZrO ₃	32
2.5.3	Antiferroelectric PbZrO ₃	33
2.5.3.1	Pb(Zr _x Ti _{1-x})O ₃ (PZT)	35
2.5.4	Relaxor Ferroelectrics	36
2.5.4.1	Relaxor Ferroelectrics: PMN- <i>x</i> PT Single Crystal	37
2.5.4.2	Polar Nano Regions	38
2.5.4.3	Morphotropic Phase Boundary (MPB) of PMN-PT Crystal	40
2.6	Ferroelectric Domain and Phase Field Calculation	41
	References	42
3	Device Applications of Ferroelectrics	47
3.1	Ferroelectric Random-Access Memory	47
3.2	Ferroelectric Tunneling Non-volatile Memory	50
3.2.1	Tunneling Models	51
3.2.2	Metal–Ferroelectric–Semiconductor Tunnel Junction	55
3.2.3	Ferroelectric Tunneling Memristor	56
3.2.4	Strain Modulation to Ferroelectric Memory	57
3.3	Pyroelectric Effect and Infrared Sensor Application	58
3.3.1	Pyroelectric Coefficient	58
3.3.2	Pyroelectric Infrared Sensor	59
3.3.3	Pyroelectric Figures of Merit	60
3.4	Application in Microwave Device	63
3.5	Ferroelectric Photovoltaics	65
3.6	Electrocaloric Effect	67
	References	68
4	Ferroelectric Characterizations	73
4.1	<i>P</i> – <i>E</i> Loop Measurement	73
4.2	Temperature-Dependent Dielectric Permittivity Measurement	76
4.3	Piezoresponse Force Microscopy (PFM)	77
4.3.1	Imaging Mechanism of PFM	77
4.3.2	Out-of-plane Polarization (OPP) and In-plane Polarization (IPP) PFM	80
4.3.2.1	Electrostatic Force in PFM	83
4.3.2.2	Perspectives of PFM Technique	84
4.4	Structural Characterization	86
4.5	Domain Imaging and Polarization Mapping by Transmission Electron Microscopy	87
4.5.1	Selected Area Electron Diffraction (SAED)	88
4.5.2	Convergent Beam Electron Diffraction (CBED) for Tetragonality Measurement	91
	References	92
5	Recent Advances in Ferroelectric Research	95
5.1	Size Limit of Ferroelectricity	95
5.2	Ferroelectricity in Emerging 2D Materials	96

5.3	Ferroelectric Vortex	99
5.4	Molecular Ferroelectrics	104
5.5	Ferroelectricity in HfO ₂ and ZrO ₂ Fluorite Oxide Thin Films	106
5.6	Ferroc Properties in Hybrid Perovskites	114
	References	117
6	Piezoelectric Effect: Basic Theory	123
6.1	General Introduction to Piezoelectric Effect	123
6.2	Piezoelectric Constant Measurement	124
6.2.1	Piezoelectric Charge Constant	125
6.2.2	Piezoelectric Voltage Constant	126
6.2.3	Dielectric Permittivity	127
6.2.4	Young's Modulus (Elastic Stiffness)	127
6.2.5	Elastic Compliance	127
6.2.6	Electromechanical Coupling Factor	128
6.2.6.1	How to Measure Electromechanical Coupling Factor?	129
6.3	Equivalent Circuit	132
6.4	Characterization of Piezoelectric Resonator Based on a Resonance Technique	135
6.4.1	Length Extensional Mode of a Rod	135
6.4.2	Extensional Vibration Mode of a Long Plate	138
6.4.3	Thickness Shear Mode of a Thin Plate	139
6.4.4	Thickness Mode of a Thin Disc/Plate	140
6.4.5	Radial Mode in a Thin Disc	141
6.4.6	Mechanical Quality Factor	141
	References	141
7	Piezoelectric Devices	143
7.1	Piezoelectric Ultrasonic Transducers	143
7.1.1	Structure of Ultrasonic Transducers	143
7.1.2	Theoretical Models of Ultrasonic Transducer (KLM Model)	145
7.1.3	Characterization of Ultrasonic Transducers	147
7.1.3.1	Bandwidth (BW)	147
7.1.3.2	Sensitivity of the Transducer	148
7.1.3.3	Resolution	148
7.1.4	Types of Ultrasonic Transducers	149
7.1.4.1	Medical Application	149
7.1.5	Piezoelectric Film Application in Ultrasound Transducers	149
7.1.6	Challenges and Trend of Developing New Advanced Ultrasound Transducers	150
7.2	Ultrasonic Motor	150
7.2.1	Terminologies	151
7.2.2	Design of USM	153
7.3	Surface Acoustics Wave Devices	154
7.3.1	Interdigital Electrode in SAW Device	155
7.3.2	Acoustic Wave	155
7.3.3	Piezoelectric Property Considerations for SAW Devices	157

7.3.4	Characterization of SAW Devices	159
7.3.5	Lead-Free Piezoelectric Materials	161
	References	163
8	Ferromagnetics: From Material to Device	165
8.1	General Introduction to Ferromagnetics	165
8.2	Ferromagnetic Phase Transition: Landau Free-Energy Theory	168
8.3	Domain and Domain Wall	169
8.4	Magnetoresistance Effect and Device	171
8.4.1	Anisotropic Magnetoresistance (AMR)	171
8.4.2	Giant Magnetoresistance (GMR)	172
8.4.3	Colossal Magnetoresistance (CMR)	175
8.4.4	Tunneling Magnetoresistance (TMR)	176
8.4.4.1	Spin-Transfer Torque Random-Access Memory (STT-RAM)	177
8.5	Magnetostrictive Effect and Device Applications	178
8.5.1	Magnetostrictive Properties of Terfenol-D	180
8.5.2	Magnetostrictive Ultrasonic Transducer	183
8.5.3	Magnetoelastic Effect	184
8.5.3.1	Magnetomechanical Strain Gauge	185
8.6	Characterizations of Ferromagnetism	186
8.6.1	Vibrating Sample Magnetometer (VSM)	186
8.6.2	Superconducting Quantum Interference Device (SQUID)	187
8.6.3	Magnetic Force Microscopy (MFM)	188
8.6.4	Magneto-Optical Kerr Effect (MOKE)	189
8.7	Hall Effect	191
8.7.1	Ordinary Hall Effect	191
8.7.2	Anomalous Hall Effect	191
8.7.3	Spin Hall Effect	192
	References	193
9	Multiferroics: Single Phase and Composites	197
9.1	Introduction on Multiferroic	197
9.2	Magnetoelectric Effect	199
9.3	Why Are There so Few Magnetic Ferroelectrics?	199
9.4	Single Phase Multiferroic Materials	200
9.4.1	Switching Mechanism in BFO Films	204
9.5	ME Composite Materials	205
9.6	Modeling the Interfacial Coupling in Multilayered ME Thin Film	207
9.6.1	PZT/CFO Multilayered Heterostructures	207
9.6.2	Ferroelectric Properties of PZT/CFO Multilayers	209
	References	212
10	Device Application of Multiferroics	217
10.1	ME Composite Devices	217
10.1.1	Effect of Preload Stress	221
10.2	Memory Devices Based on Multiferroic Thin Films	223

10.3	Memory Devices Based on Multiferroic Tunneling	224
	References	229
11	Ferroelasticity and Shape Memory Alloy	231
11.1	Shape Memory Alloy	231
11.1.1	SMA Phase Change Mechanism	232
11.1.2	Nonlinearity in SMA	233
11.1.3	One-Way and Two-Way Shape Memory Effect	235
11.1.4	Superelastic Effect (SE)	235
11.1.5	Application Examples of SMAs	236
11.2	Ferromagnetic Shape Memory Alloys	237
11.2.1	Formation of Twin Variants	238
11.2.2	Challenges for Ni–Mn–Ga SMA	242
11.2.3	Device Application of MSMA	243
	References	244
	Index	247

